

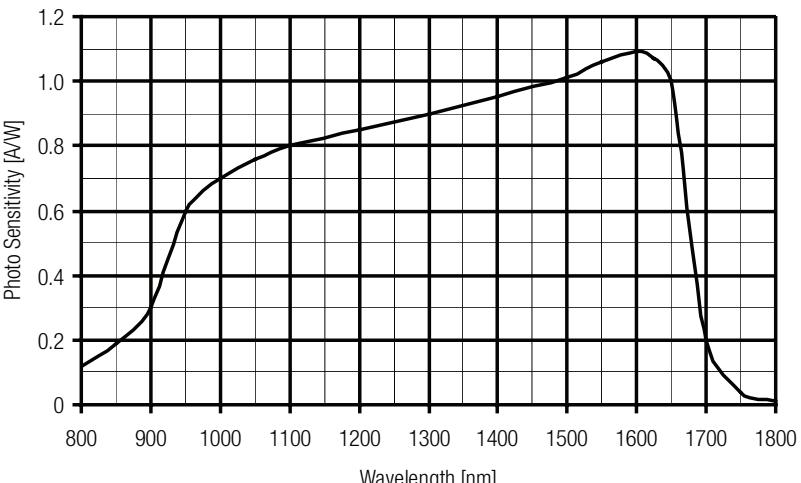
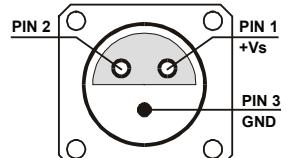
Ultra High Speed Photoreceiver with InGaAs Photodiode



The photoreceiver will be delivered without post holder and post

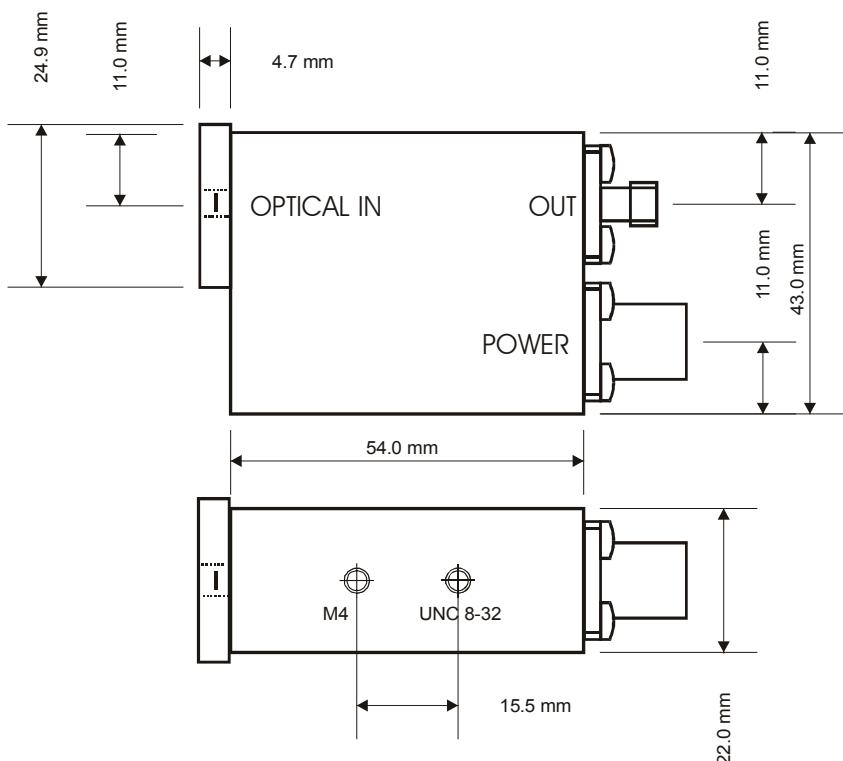
Features	<ul style="list-style-type: none"> Bandwidth 10 kHz ... 2 GHz InGaAs Detector, Ø 0.2 mm Effective Active Diameter Spectral Range 850 ... 1700 nm Amplifier Transimpedance (Gain) 5×10^3 V/A Max. Conversion Gain 4.8×10^3 V/W @ 1550 nm 		
Applications	<ul style="list-style-type: none"> Spectroscopy Ultra Fast Pulse and Transient Measurements Optical Triggering Optical Front-End for Oscilloscopes and Ultra Fast A/D Converters 		
Specifications	<i>Test Conditions</i>	$V_s = + 15 V, T_a = 25^\circ C, System Impedance = 50 \Omega$	
Gain	Amplifier Transimpedance	5×10^3 V/A	(@ 50 Ω load)
	Conversion Gain	4.8×10^3 V/W	(@ 1550 nm)
Frequency Response	Lower Cut-Off Frequency	10 kHz	
	Upper Cut-Off Frequency	2 GHz	(-3 dB)
	Rise/Fall Time	180 ps	(10% - 90%)
	Gain Flatness	± 1 dB	
Input / Detector	Detector Material	InGaAs photodiode	
	Active Area	effective Ø 0.2 mm (actual Ø 0.1 mm plus ball lens)	
	Spectral Range	850 ... 1700 nm	
	Max. Optical Input-Power	240 μ W	(for linear amplification, @ 1550 nm)
Noise	Min. NEP	14 pW/ $\sqrt{\text{Hz}}$	(@ 1550 nm, 100 MHz)
Output	Output Impedance	50 Ω	
	Output Peak Voltage	1.9 Vpp	(@ 50 Ω load, for linear amplification)
Power Supply	Supply Voltage	+ 15 V, 130 mA typ. (depends on operating conditions, recommended power supply capability minimum 200 mA)	

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Case	Weight Material	100 g (0.23 lbs) AlMg4.5Mn, nickel-plated																								
Temperature Range	Storage Temperature Operating Temperature	-40 ... +100 °C 0 ... +60 °C																								
Absolute Maximum Ratings	Power Supply Voltage Optical Input Power	± 22 V 10 mW (averaged)																								
Spectral Response	 <table border="1"> <caption>Data points estimated from the spectral response graph</caption> <thead> <tr> <th>Wavelength [nm]</th> <th>Photo Sensitivity [A/W]</th> </tr> </thead> <tbody> <tr><td>800</td><td>0.15</td></tr> <tr><td>900</td><td>0.25</td></tr> <tr><td>1000</td><td>0.65</td></tr> <tr><td>1100</td><td>0.80</td></tr> <tr><td>1200</td><td>0.85</td></tr> <tr><td>1300</td><td>0.90</td></tr> <tr><td>1400</td><td>0.95</td></tr> <tr><td>1500</td><td>1.00</td></tr> <tr><td>1600</td><td>1.10</td></tr> <tr><td>1700</td><td>0.20</td></tr> <tr><td>1800</td><td>0.05</td></tr> </tbody> </table>		Wavelength [nm]	Photo Sensitivity [A/W]	800	0.15	900	0.25	1000	0.65	1100	0.80	1200	0.85	1300	0.90	1400	0.95	1500	1.00	1600	1.10	1700	0.20	1800	0.05
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Connectors	<p>Input: optical, free space, 25 mm Ø round flange compatible with microbench systems</p> <p>Output: SMA</p> <p>Power Supply: LEMO series 1S, 3-pin fixed socket Pin 1: +15V Pin 2: n.c. Pin 3: GND</p> 																									

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Dimensions



DZ-HSA-X-S_3.cdr

FEMTO Messtechnik GmbH
Paul-Lincke-Ufer 34
D-10999 Berlin • Germany
Tel.: +49 (0)30 – 4 46 93 86
Fax: +49 (0)30 – 4 46 93 88
E-Mail: info@femto.de
<http://www.femto.de>

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